

SUF 5404	Sym	Si-Di	=SUF 5400: 400V	31a	DO-27A		EGP 30G, FE 3H
<b>SV...SX</b>							
SV-1...-3	Sak	Si-Varistor	VDR/Varistor	31	(6x110)		
SV-02...-06(S)	Sak	Si-Varistor	VDR/Varistor	(S: DO-41 31	DO-14		
SV 3-7015		Si-N	=2SC1226			BD 243 C 17j	*2SC1226
SV-9		Si-Di	=BA 127	31a		1N4148 31a	*BA 127
SV 31		Si-Di	=1S188	31a		1N4148 31a	*1S188
SW		Z-Di	=SM 4T 100 (SMD-Marking)	71a(6x4mm)	SOD-6		*SM 4T...
SW 153, 172, 173, 174, 180, 185, 203 250, 260, 303, 453	Pls	SAW-Filter	TV, Oberflächenwellenfilter/SAW Filter (Surface Acoustic Wave)	2/4...8Pin	=TO-8		
		Z-Di	=SM 4T 100A (SMD-Marking)	71a(6x4mm)	SOD-6		*SM 4T...
SX 3702		Si-P	=2N3702	7a	TO-92	BC 556 7a	
SXT 2222A	Sie	Si-N	=2N2222A: SMD	39b	SOT-89		BCX 55...56, PXT 2222A, 2SD1005...1006, ++
SXT 2907A	Sie	Si-P	=2N2907A: SMD	39b	SOT-89		BCX 52...53, PXT 2907A, 2SB803...805, ++
SXT 3904	Sie	Si-N	=2N3904: SMD	39b	SOT-89		PXT 3904, 2SC3803
SXT 3906	Sie	Si-P	=2N3906: SMD	39b	SOT-89		PXT 3906, 2SA1483
SXTA 42	Sie	Si-N	=MPS-A42: SMD	39b	SOT-89		-
SXTA 43	Sie	Si-N	=MPS-A43: SMD	39b	SOT-89		-
SXTA 92	Sie	Si-P	=MPS-A92: SMD	39b	SOT-89		-
SXTA 93	Sie	Si-P	=MPS-A93: SMD	39b	SOT-89		-
<b>SY...SZ</b>							
SY		Si-P	=2SA1162-Y (SMD-Marking)	35	SOT-23		*2SA1162
SY		Si-P	=2SA1586-Y (SMD-Marking)	35(2mm)	SOT-323		*2SA1586
SY		Si-P	=2SA1618-Y (SMD-Marking)	45	SOT-153		*2SA1618
SY		Si-P	=2SA1832-Y (SMD-Marking)	35(1,6mm)	SS Mini		*2SA1832
SY		Si-P	=2SA1873-Y (SMD-Marking)	45(2mm)	SOT-353		*2SA1873
SY		Si-N	=2SC3900 (SMD-Marking)	35	SOT-23		*2SC3900
SY 100	Hfo	Si-Di	Rr, Uni, 75V, 1A	32a		BY 329/1200 <sup>4</sup> 17k	(BY 205/100, BY 229/200, BY 249/300, ++) <sup>4</sup>
SY 101	Hfo	Si-Di	=SY 100: 100V	32a		BY 329/1200 <sup>4</sup> 17k	(BY 205/100, BY 229/200, BY 249/300, ++) <sup>4</sup>
SY 102	Hfo	Si-Di	=SY 100: 200V	32a		BY 329/1200 <sup>4</sup> 17k	(BY 205/200, BY 229/200, BY 249/300, ++) <sup>4</sup>
SY 103	Hfo	Si-Di	=SY 100: 300V	32a		BY 329/1200 <sup>4</sup> 17k	(BY 205/400, BY 229/400, BY 249/600, ++) <sup>4</sup>
SY 104	Hfo	Si-Di	=SY 100: 400V	32a		BY 329/1200 <sup>4</sup> 17k	(BY 205/400, BY 229/400, BY 249/600, ++) <sup>4</sup>
SY 105	Hfo	Si-Di	=SY 100: 500V	32a		BY 329/1200 <sup>4</sup> 17k	(BY 205/600, BY 229/600, BY 249/600, ++) <sup>4</sup>
SY 106	Hfo	Si-Di	=SY 100: 600V	32a		BY 329/1200 <sup>4</sup> 17k	(BY 205/600, BY 229/600, BY 249/600, ++) <sup>4</sup>
SY 107	Hfo	Si-Di	=SY 100: 700V	32a		BY 329/1200 <sup>4</sup> 17k	(BY 205/800, BY 229/800, ++) <sup>4</sup>
SY 108	Hfo	Si-Di	=SY 100: 800V	32a		BY 329/1200 <sup>4</sup> 17k	(BY 205/800, BY 229/800, ++) <sup>4</sup>
SY 110	Hfo	Si-Di	=SY 100: 1000V	32a		BY 329/1200 <sup>4</sup> 17k	(BY 205/1000, BY 229/1000, ++) <sup>4</sup>
SY 120	Hfo	Si-Di	=SY 100:	32b		BY 329/1200 <sup>4</sup> 17k	(BY 205/100, BY 229/200, BY 249/300, ++) <sup>4</sup>
SY 121	Hfo	Si-Di	=SY 101:	32b		BY 329/1200 <sup>4</sup> 17k	(BY 205/100, BY 229/200, BY 249/300, ++) <sup>4</sup>
SY 122	Hfo	Si-Di	=SY 102:	32b		BY 329/1200 <sup>4</sup> 17k	(BY 205/200, BY 229/200, BY 249/300, ++) <sup>4</sup>
SY 123	Hfo	Si-Di	=SY 103:	32b		BY 329/1200 <sup>4</sup> 17k	(BY 205/400, BY 229/400, BY 249/300, ++) <sup>4</sup>
SY 124	Hfo	Si-Di	=SY 104:	32b		BY 329/1200 <sup>4</sup> 17k	(BY 205/400, BY 229/400, BY 249/600, ++) <sup>4</sup>
SY 125	Hfo	Si-Di	=SY 105:	32b		BY 329/1200 <sup>4</sup> 17k	(BY 205/600, BY 229/600, BY 249/600, ++) <sup>4</sup>
SY 126	Hfo	Si-Di	=SY 106:	32b		BY 329/1200 <sup>4</sup> 17k	(BY 205/600, BY 229/600, BY 249/600, ++) <sup>4</sup>
SY 127	Hfo	Si-Di	=SY 107:	32b		BY 329/1200 <sup>4</sup> 17k	(BY 205/800, BY 229/800, ++) <sup>4</sup>
SY 128	Hfo	Si-Di	=SY 108:	32b		BY 329/1200 <sup>4</sup> 17k	(BY 205/800, BY 229/800, ++) <sup>4</sup>
SY 130	Hfo	Si-Di	=SY 110:	32b		BY 329/1200 <sup>4</sup> 17k	(BY 205/1000, BY 229/1000, ++) <sup>4</sup>
SY 200	Hfo	Si-Di	Rr, Uni, 75V, 0,95A	34a	=DO-1	BY 133 31a	BY 126...127, BY 133...135, 1N4002...07, ++
SY 201	Hfo	Si-Di	=SY 200: 100V	34a	=DO-1	BY 133 31a	BY 126...127, BY 133...135, 1N4002...07, ++
SY 202	Hfo	Si-Di	=SY 200: 200V	34a	=DO-1	BY 133 31a	BY 126...127, BY 133...134, 1N4003...07, ++
SY 203	Hfo	Si-Di	=SY 200: 300V	34a	=DO-1	BY 133 31a	BY 126...127, BY 133...134, 1N4004...07, ++
SY 204	Hfo	Si-Di	=SY 200: 400V	34a	=DO-1	BY 133 31a	BY 126...127, BY 133...134, 1N4004...07, ++
SY 205	Hfo	Si-Di	=SY 200: 500V	34a	=DO-1	BY 133 31a	BY 126...127, BY 133...134, 1N4005...07, ++
SY 206	Hfo	Si-Di	=SY 200: 600V	34a	=DO-1	BY 133 31a	BY 126...127, BY 133...134, 1N4005...07, ++
SY 207	Hfo	Si-Di	=SY 200: 700V	34a	=DO-1	BY 133 31a	BY 127, BY 133, BY 227, 1N4006...07, ++
SY 208	Hfo	Si-Di	=SY 200: 800V	34a	=DO-1	BY 133 31a	BY 127, BY 133, BY 227, 1N4006...07, ++
SY 210	Hfo	Si-Di	=SY 200: 1000V	34a	=DO-1	BY 133 31a	BY 127, BY 133, BY 227, 1N4007, ++
SY 220	Hfo	Si-Di	=SY 200:	34b	=DO-1	BY 133 31a	*SY 200
SY 221	Hfo	Si-Di	=SY 201:	34b	=DO-1	BY 133 31a	*SY 201
SY 222	Hfo	Si-Di	=SY 202:	34b	=DO-1	BY 133 31a	*SY 202
SY 223	Hfo	Si-Di	=SY 203:	34b	=DO-1	BY 133 31a	*SY 203
SY 224	Hfo	Si-Di	=SY 204:	34b	=DO-1	BY 133 31a	*SY 204
SY 225	Hfo	Si-Di	=SY 205:	34b	=DO-1	BY 133 31a	*SY 205
SY 226	Hfo	Si-Di	=SY 206:	34b	=DO-1	BY 133 31a	*SY 206
SY 227	Hfo	Si-Di	=SY 207:	34b	=DO-1	BY 133 31a	*SY 207
SY 228	Hfo	Si-Di	=SY 208:	34b	=DO-1	BY 133 31a	*SY 208
SY 230	Hfo	Si-Di	=SY 210:	34b	=DO-1	BY 133 31a	*SY 210
SY 320/0,75...10	Hfo	Si-Di	Rr, Uni, 75...1000V, 0,95A	31a	DO-26	BY 133 31a	BY 126...127, BY 133...135, 1N4002...07, ++
SY 330/1...10	Hfo	Si-Di	FRr, 100...1000V, 0,27...0,43A, <500ns	31a	DO-26	BA 159 31a	BA 157...159, BY 204...208, ++
SY 330/12...20	Hfo	Si-Di	FRr, 1200...2000V, 0,16...0,24A, <500ns	31a	DO-15	BY 203/20 31a	BY 203/...
SY 335/05K...8K	Hfo	Si-Di	FRr, 50...800V, 1...1,4A, <500ns	31a	DO-26	BYD 33 M 31a	BY 258/..., BYV 12...16, RGP 15A...M, ++
SY 335/05L...8L	Hfo	Si-Di	FRr, 50...800V, 1...1,4A, <1µs	31a	DO-26	BYD 33 M 31a	BY 258/..., BYV 12...16, RGP 15A...M, ++
SY 345/05K...10K	Hfo	Si-Di	FRr, 50...1000V, 1,1...1,4A, <500ns	31a	DO-15	BYD 33 M 31a	BY 258/..., BYV 12...16, RGP 15A...M, ++
SY 345/05L...10L	Hfo	Si-Di	FRr, 50...1000V, 1,1...1,4A, <1µs	31a	DO-15	BYD 33 M 31a	BY 258/..., BYV 12...16, RGP 15A...M, ++
SY 346/05...10	Hfo	Si-Di	FRr, 50...1000V, 0,59...0,81A, 200ns	31a	DO-15	BYD 33 M 31a	BYT 52A...M, BYV 12...16, RG 1A...M, ++
SY 347/05...10	Hfo	Si-Di	FRr, 50...1000V, 0,53...0,73A, 200ns	31a	DO-15	BYD 33 M 31a	BYT 52A...M, BYV 12...16, RG 1A...M, ++
SY 351/05...14	Hfo	Si-Di	Rr, Uni, 50...1400V, 3A	31a	DO-26	BY 228 31a	BY 251...255, BY 228, BY 448, ++
SY 356/05...10	Hfo	Si-Di	FRr, 50...1000V, 1,5A, 300ns	31a	DO-15	BYD 33 M 31a	BYV 12...16, BYV 36A...E, RG 2A...M, ++
SY 360/0,5...10	Hfo	Si-Di	Rr, Uni, 50...1000V, 0,9A	31a	DO-15	BY 133 31a	BY 126...127, BY 133...135, 1N4001...07, ++
SY 361/10...13	Hfo	Si-Di	Rr, 1000...1300V, 1A	31a	DO-15	BY 228 31a	BY 228, BY 231/1500, DM 513, GP 10V...Y
SY 361/16		Si-Di	=SY 361/10...13: 1600V	31a	DO-15	BY 228 31a	BY 228, BY 231/1500, DM 516, GP 10V
SY 361/18		Si-Di	=SY 361/10...13: 1800V	31a	DO-15		-
SY 400/0,75...10	Hfo	Si-Di	Rr, Uni, 75...1000V, 2A	34	=DO-1	BY 255 31a	BY 251...255, BY 259/..., GP 20A...M, ++
SZ... sZC		Z-Di		31a		Z-Diode ...V 31a	
		Si-N	=SMBT 4124 (SMD-Marking)	35	SOT-23		*SMBT 4124
<b>T</b>							
T		N-FET	=2SK1065 (SMD-Marking)	35	SOT-23		*2SK1065
T		GaAs-N-FET	=2SK1615 (Marking)	51	SOT-173		*2SK1615
T 0,8N/0,6...5[ITT]	Itt	50Hz-Thy	60...500V, 0,8A(Tc=85°C), Igt/Ih<10<20mA	2a	TO-39		BTX 30/..., T 1N... S 2600..., TAG 612-...